CREATIVE GMBH LED

Preliminary Product Specification

Phototransistor 8° CSR68581PBK

* Phototransistor with separate Base for general purpose
* Mountable in row with 5mm distance
* **Response Angle of typ. 8 degree with a pointed tip**
* Daylight filtered black housing
* Mechanical matched with CQR6 -serie
* SMT-Version CSS68581PBK

Optical and Electrical Characteristics @Tambient =25°C

Symbol	Parameter	MIN	Typ	MAX	UNIT	Test conditions
I_{Light}	Collector Light Current	13	20		mA	Ee = 1mW/cm² @940nm ; Vr=10V
I_{CEO}	Collector Dark Current		1		nA	Ee = 0 mW/cm² ; Vr=10V
$V_{(BR)CEO}$	Collector Emitter Breakdown Voltage	30			V	Ic = 100 µA ; Ib = 0
$V_{(BR)ECO}$	Emitter Collector Breakdown Voltage	5			V	Ie = 100 µA ; Ib = 0
V_{CEsat}	Collector-Emitter Saturation Voltage		0,3		V	Ib = 100µA Ic = 2mA
λ_{peak}	Wavelength of Peak Sensitivity		860		nm	max. sensitivity
$\lambda_{0,5}$	Range of Spectral Bandwidth	720		1050	nm	I = 10%, typical
t_f	Fall Time		15		µS	Vce = 5V ; Ic = 1mA ; RL = 1KΩ
t_r	Rise Time		15		µS	Vce = 5V ; Ic = 1mA ; RL = 1KΩ
A	Active Array		0,145		mm²	
ß	Current Gain	500		1000	0	Vce = 5 V ; Ic = 2mA
$2\Phi_{0,5}$	Full Response Angle		8		deg.	ΦE = 50%
C_{CEO}	Collector Emitter Capacitance		6		pF	VR = 5V ; f = 1Mhz; Ee = 0mW/cm²
$T_{Operating}$	Operating Temperature	-30		85	°C	
$T_{Storage}$	Storage Temperature	-30		100	°C	
$T_{Soldering}$	Soldering Temperature			260	°C	Iron Soldering; 5mm from case @ max 5 sec.
R_{thJA}	Thermal Resistance		450		K/W	
P_{tot}	Total Power Dissipation			50	mW	Tamb 25°C

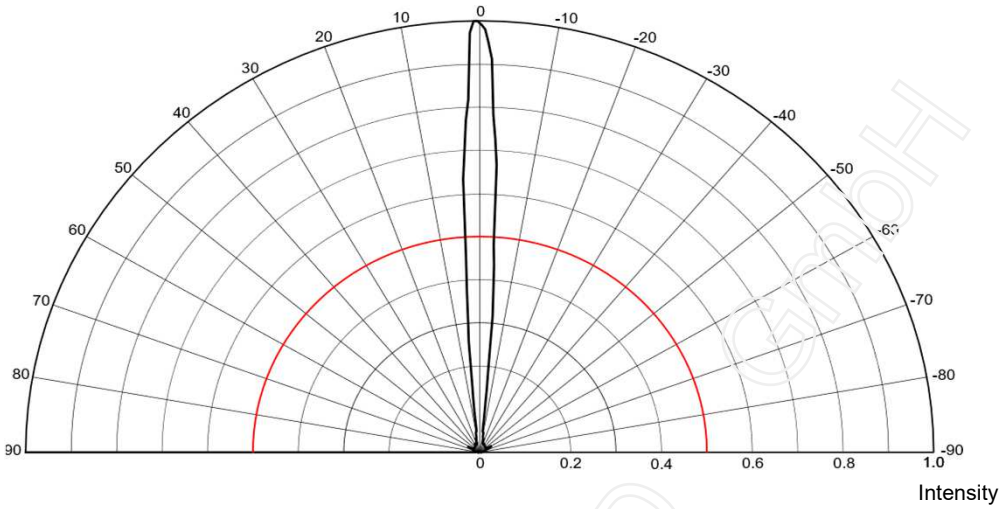
Order informations:

CSR68581PBK	Bulk
CSR68581PBK-TC	Bended according to customer specifications (on request)

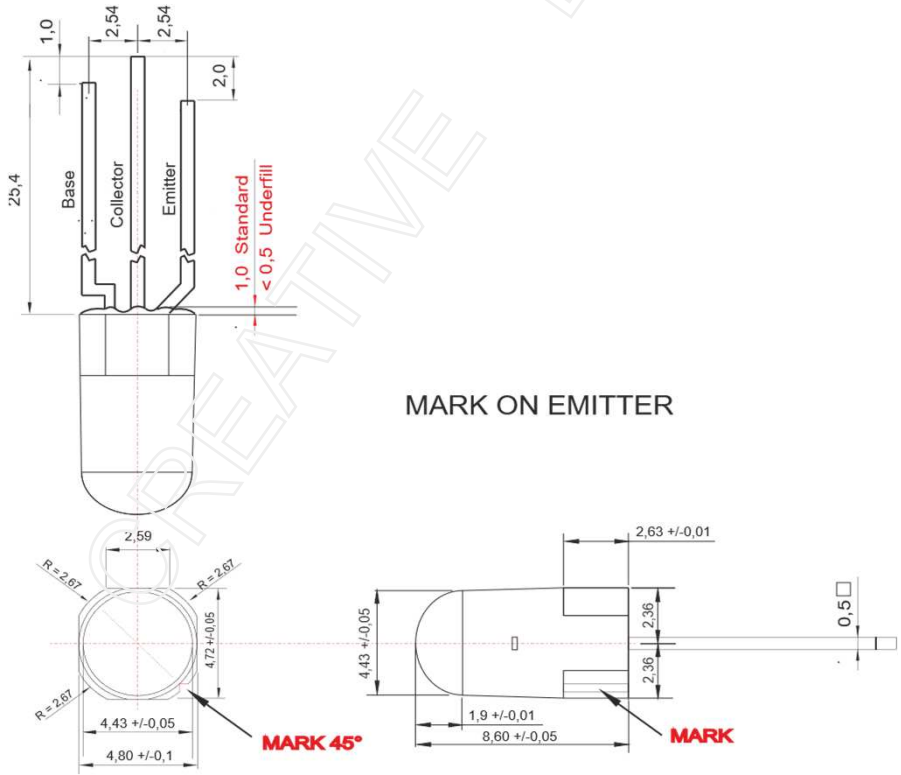
CSR68581PBK

Relative Radiation Sensitivity

@ $T_{ambient}$ = 25°C



Mechanical Drawing



Pls. Contact us for more technical detail information !